

**DCC010** 

Silicon Epitaxial Planar Type (Series Connection)

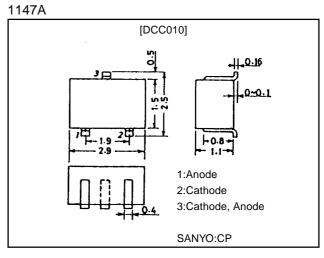
# **Ultrahigh-Speed Switching Diode**

#### Features

- · Ideally suited for use in hybrid ICs because of very small package.
- · Fast switching speed.
- · Small interterminal capacitance.

### **Package Dimensions**

unit:mm



## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

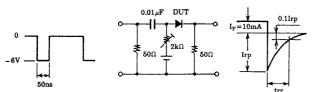
Parameter	Symbol	Conditions	Ratings	Unit
Peak Reverse Voltage	V <sub>RM</sub>		85	V
Reverse Voltage	V <sub>R</sub>		80	V
Peak Forward Current	IFM	Unit Rating	300	mA
			210	mA
Average Rectified Current	IO	Unit Rating	100	mA
			70	mA
Surge Current (1µs)	IFSM	Unit Rating	4	А
			2.8	А
Power Dissipation	Р		200	mW
Junction Temperature	Tj		125	°C
Storage Temperature	Tstg		-55 to +125	°C

#### Electrical Characteristics at Ta = 25°C

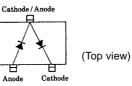
Parameter	Symbol	Conditions	Ratings			Unit
Falanielei			min	typ	max	
Forward Voltage	V <sub>F</sub> (1)	I <sub>F</sub> =1mA		0.60		V
	V <sub>F</sub> (2)	I <sub>F</sub> =10mA		0.72		V
	V <sub>F</sub> (3)	I <sub>F</sub> =100mA			1.20	V
Reverse Current	I <sub>R</sub> (1)	V <sub>R</sub> =30V			0.1	μΑ
	I <sub>R</sub> (2)	V <sub>R</sub> =80V			0.5	μΑ
Interterminal Capacitance	С	V <sub>R</sub> =0V, f=1MHz			3.0	pF
Reverse Recovery Time	trr	I <sub>F</sub> =10mA, V <sub>R</sub> =6V, R <sub>L</sub> =50Ω, Irr=0.1Irp			4.0	ns

· Marking:W7

#### **Reverse Recovery Time Test Circuit**



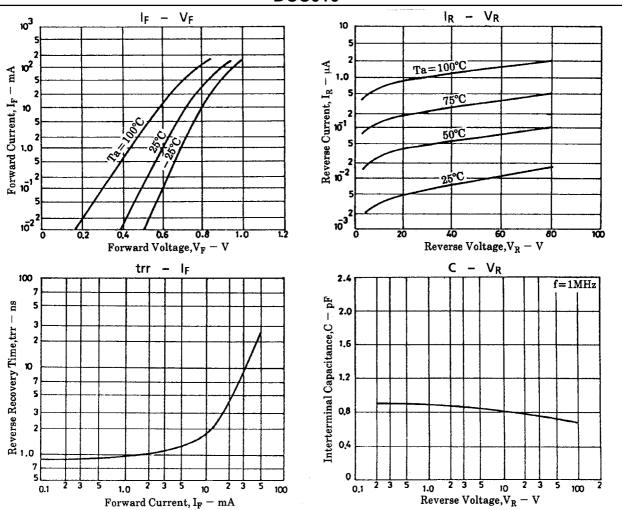
#### **Electrical Connection**



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